

One-dimensional Dirac modes of a pentagonal topological crystalline insulator nanowires

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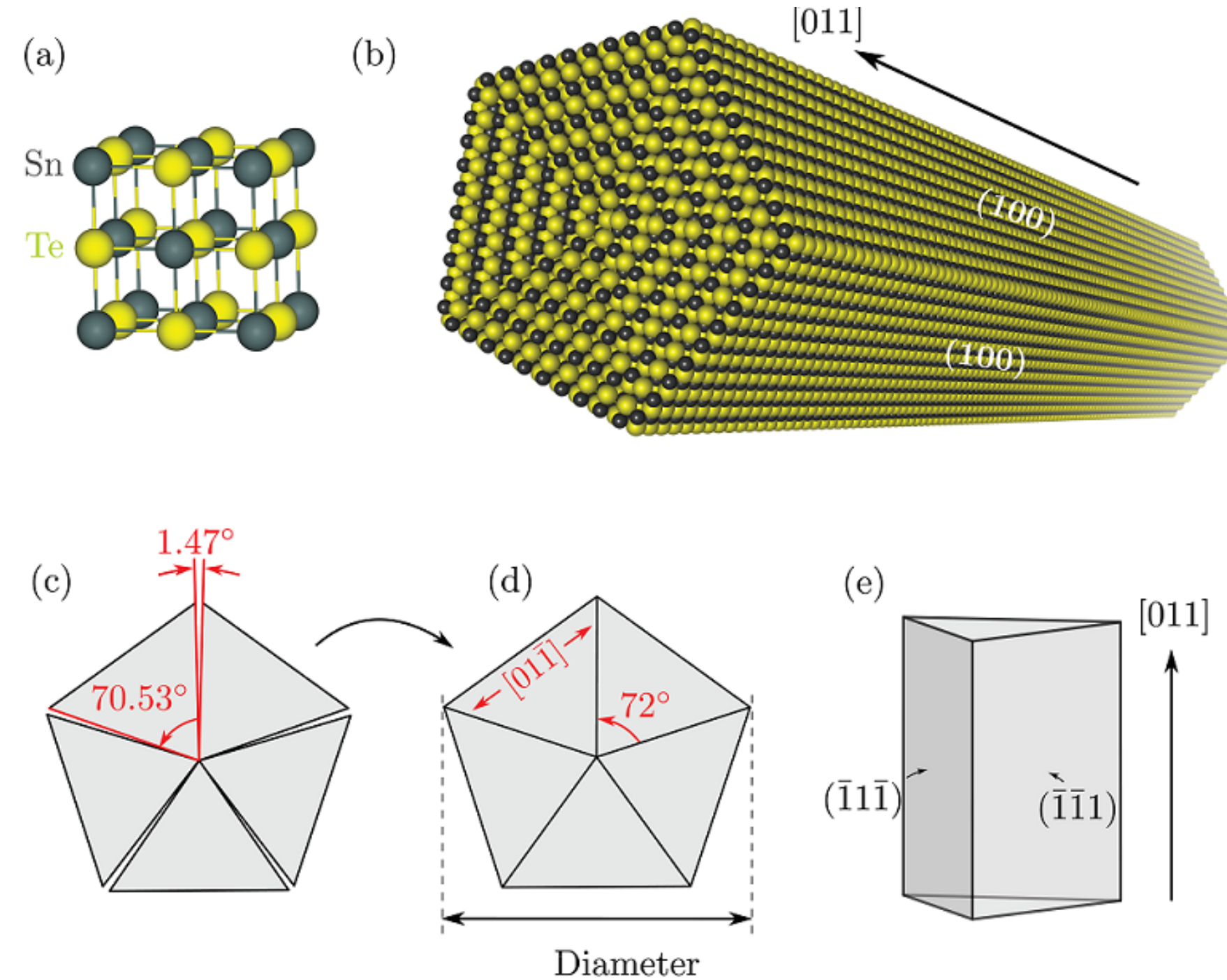
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IV-VI semiconductor pentagonal nanowires

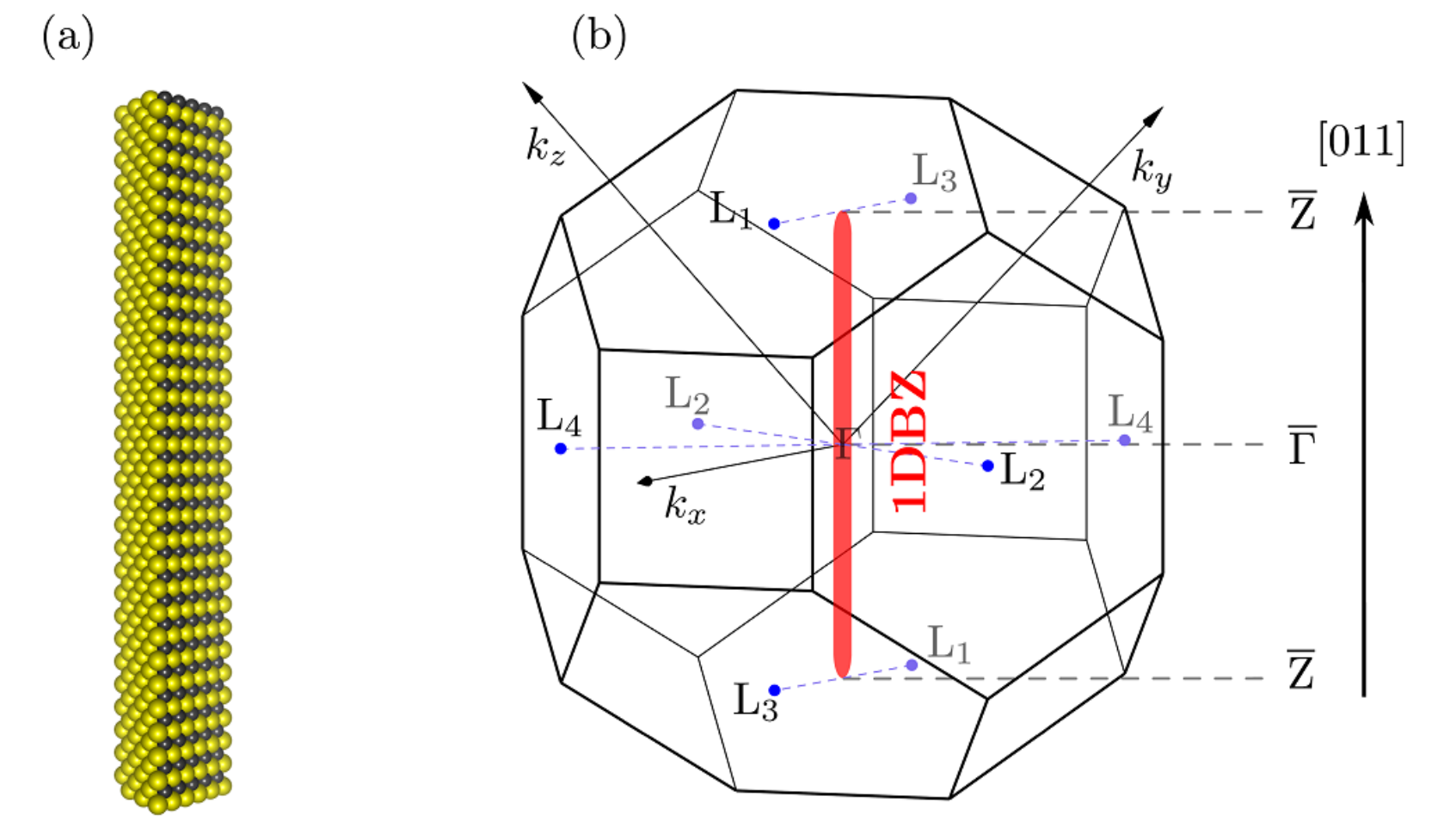
IV-VI compounds are categorized as a narrow bandgap semiconductors. In particular, SnTe has inverted band gap and is identified as a topological crystalline insulator (TCIs). The band gap occurs in four non-equivalent high symmetry L points in the reciprocal space [1]. Five-fold NWs have been recently grown and demonstrated by transmission electron microscopic measurement [2].

- The NWs are grown along [011] direction
- They have five {111} twin plane (TP) boundaries; either exclusively cationic or anionic
- Five {100} free surfaces
- NWs have inherent circumferential strain (by the angle 1.47°)
- topological phase remains unchanged due to this strain
- The gap changes are less than 10% respect to unstrained bulk crystal for SnTe and less than 20% for $\text{Pb}_{0.6}\text{Sn}_{0.4}\text{Se}$

Pentagonal modeled structure



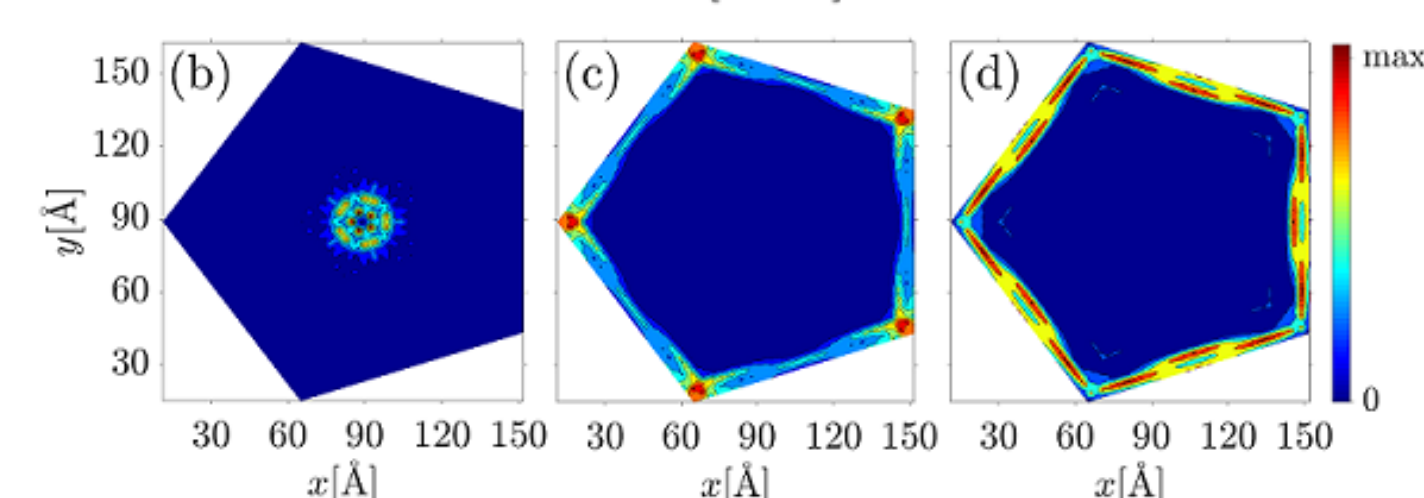
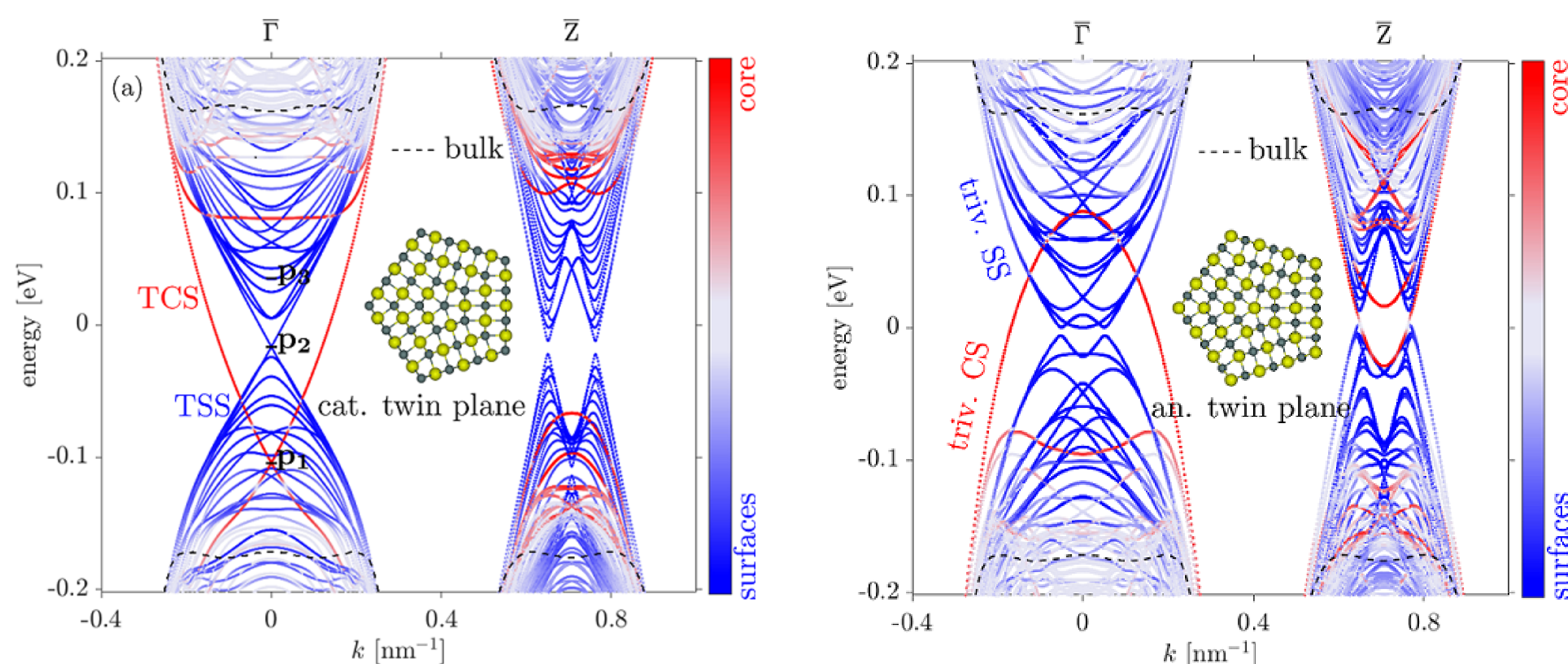
3D & 1D Brillouin zone



- Perspective of one triangle of pentagonal NW (Fig. a)
- The band gaps are placed in two distinct $\bar{\Gamma}$ and \bar{Z} points in 1DBZ
- 1DBZ is the same for each triangle of NW

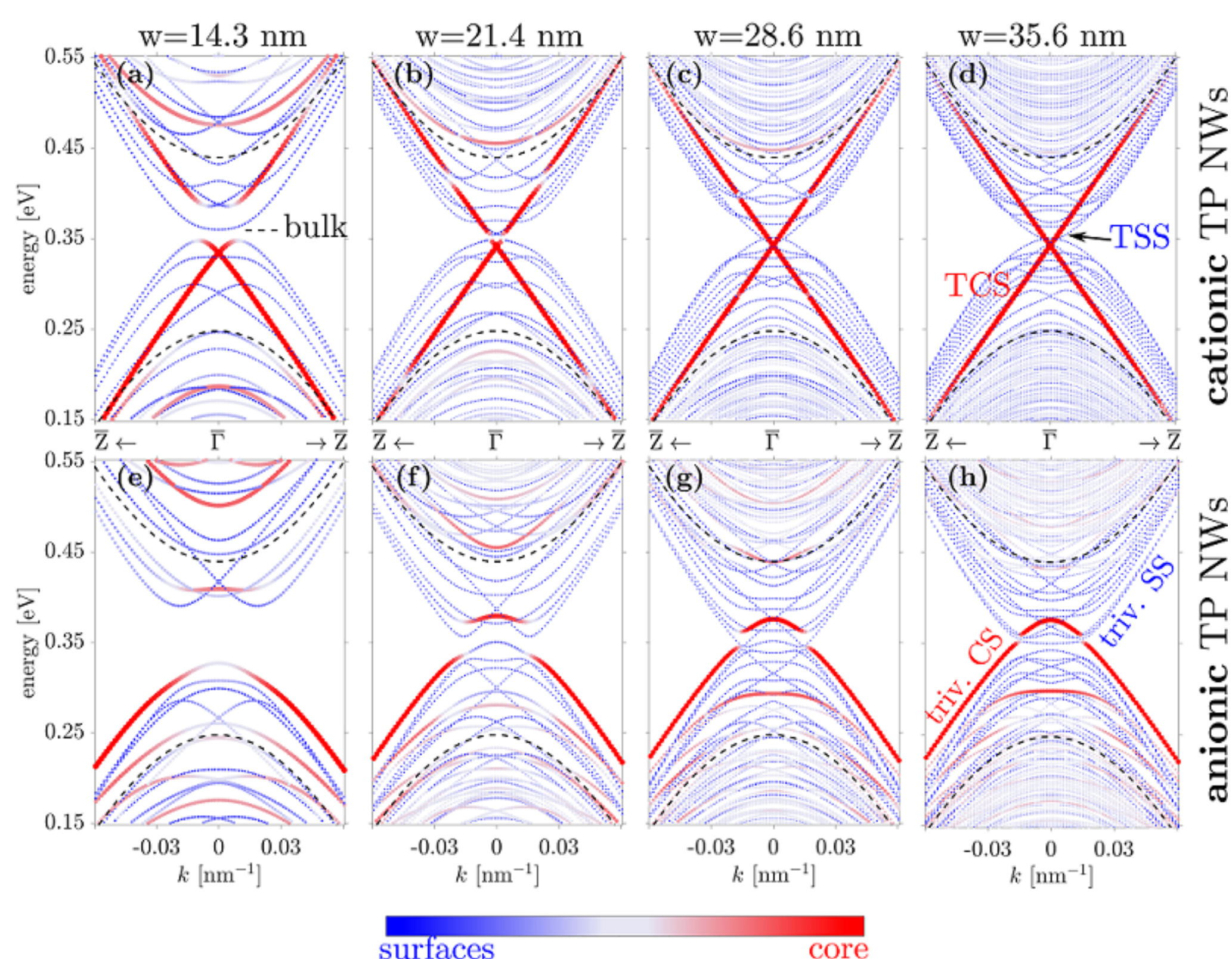
Tight-binding band structure of pentagonal nanowires

Band structure calculations have been performed using simplified tight-binding (TB) parameterization with p orbitals for SnTe and realistic sp^3d^5 parameterization for $(\text{Pb},\text{Sn})\text{Se}$ [3]. The bulk band gaps are -0.33 eV for SnTe and -0.19 eV for $\text{Pb}_{0.6}\text{Sn}_{0.4}\text{Se}$.



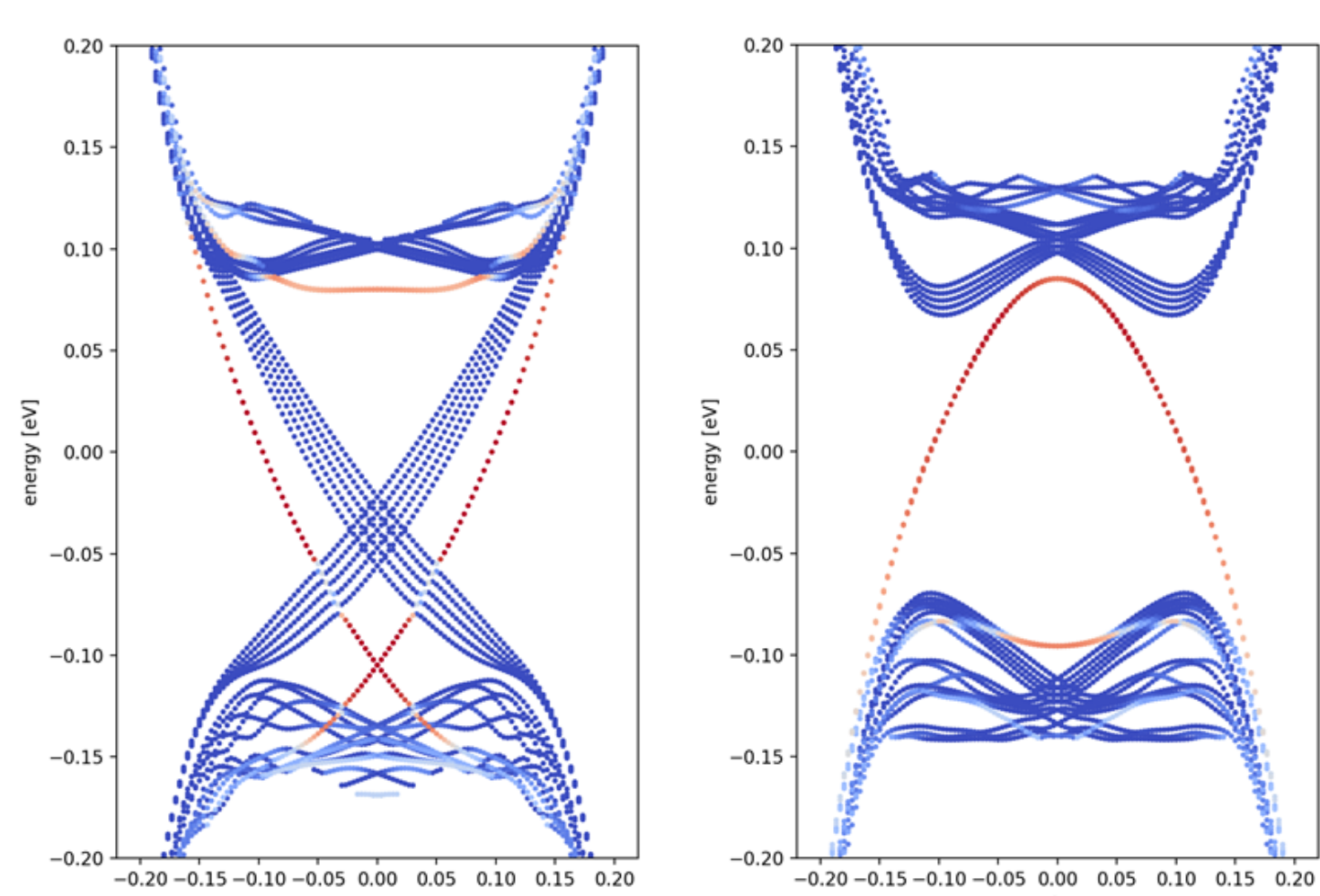
Right: Electronic structure for SnTe pentagonal NW with anionic TPs. Observation of topologically trivial (triv.) core states (CS) and surface states (SSs) obtained for 14 nm (20 rings) thickness.

Left: (a) Electronic structure for SnTe pentagonal NW with cationic TPs. Observation of topological CS and topological SSs obtained for 14 nm (20 rings). (b-d) Spatial distribution of localized CS (at p_1), hybridized hinge states (at p_2) and conventional TCI SSs (at p_3) presented by sum of the squared moduli of the wave functions, respectively.



Electronic structure for $\text{Pb}_{0.6}\text{Sn}_{0.4}\text{Se}$ pentagonal NW. Upper row: Topological CS is presented in cationic TPs. Due to confinement effect the CS hybridizes with SSs and open the gap (a,b). Lower row: Panels (e)-(f) represent the anti-crossing triv. CS for anionic TP NWs.

Hinge states in a pentagonal NWs



- imposing perturbation to the atoms where located at the faces of pentagonal wire
- breaking all relevant mirror symmetries
- introducing on-site potential at each hinge (breaking C_5)

Left: Cationic TPs, one topological CS (red) and five topological hinge states. Right: Anionic TPs, no Dirac crossings become visible.

Low-energy theory of the core and hinge states

The $k \cdot p$ Hamiltonian can be written as

$$H_\lambda(k_z) = \epsilon_{0,\lambda} + \begin{pmatrix} \Delta_\lambda & e^{i\frac{\pi}{10}} v_\lambda k_z \\ e^{-i\frac{\pi}{10}} v_\lambda k_z & -\Delta_\lambda \end{pmatrix} \quad (1)$$

where C_5 eigenvalue is

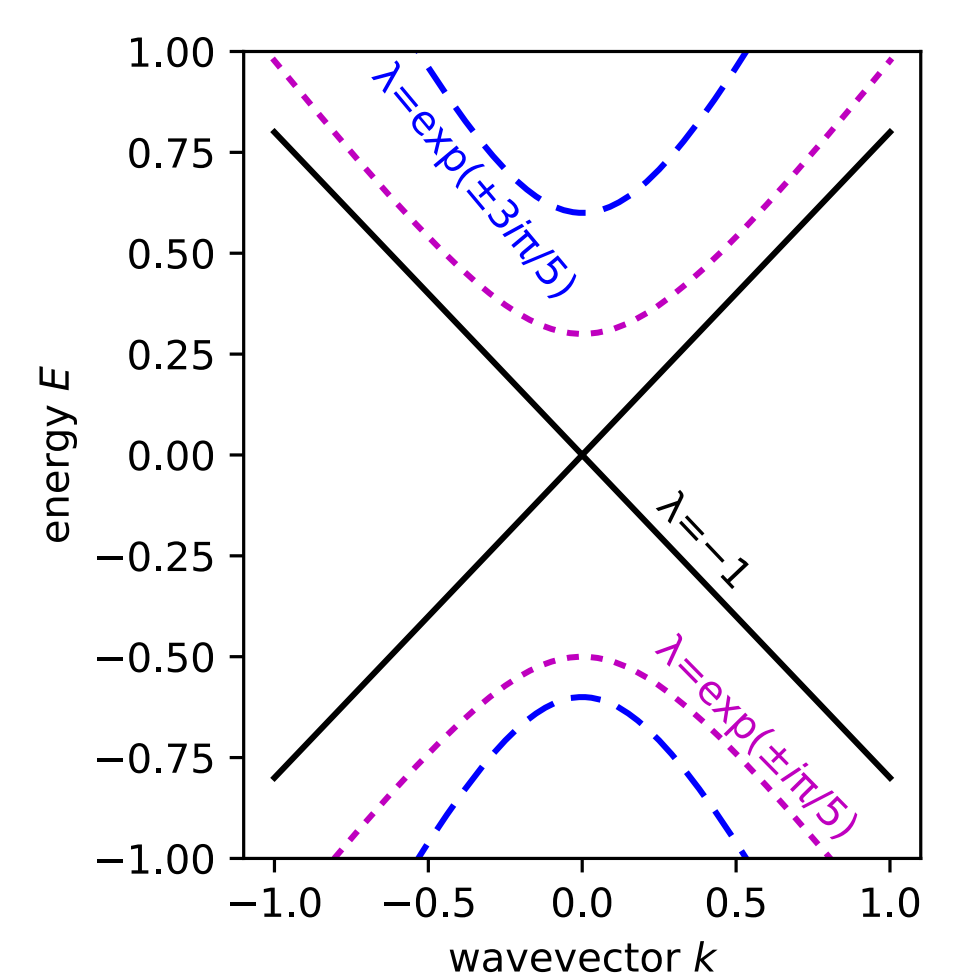
$$\lambda \in \left\{ -1, e^{i\frac{\pi}{5}}, e^{-i\frac{\pi}{5}}, e^{i\frac{3\pi}{5}}, e^{-i\frac{3\pi}{5}} \right\} \quad (2)$$

The real valued parameters $\epsilon_{0,\lambda}$, Δ_λ , and v_λ satisfy constraints

$$\Delta_{\lambda^*} = -\Delta_\lambda, \quad v_{\lambda^*} = v_\lambda, \quad \epsilon_{0,\lambda^*} = \epsilon_{0,\lambda}. \quad (3)$$

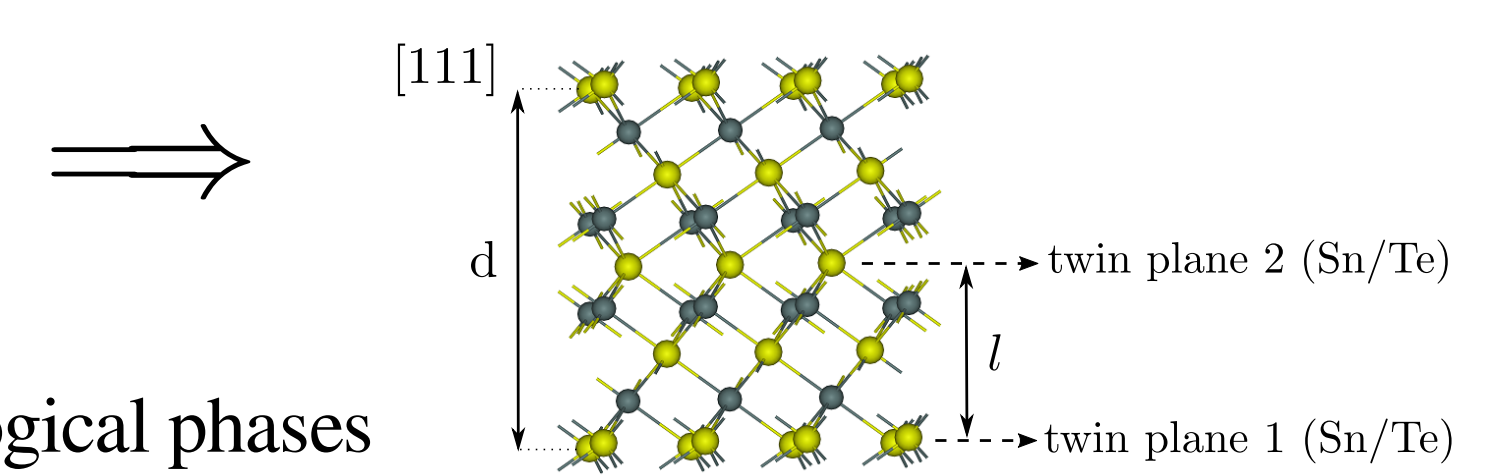
Consequences:

- symmetry dictates $\Delta_{-1} = 0$
- spectrum in the subspace $\lambda = -1$ is gapless (Dirac crossing)



Topological phases of twin planes

[111] heterostructure constructed with twin planes

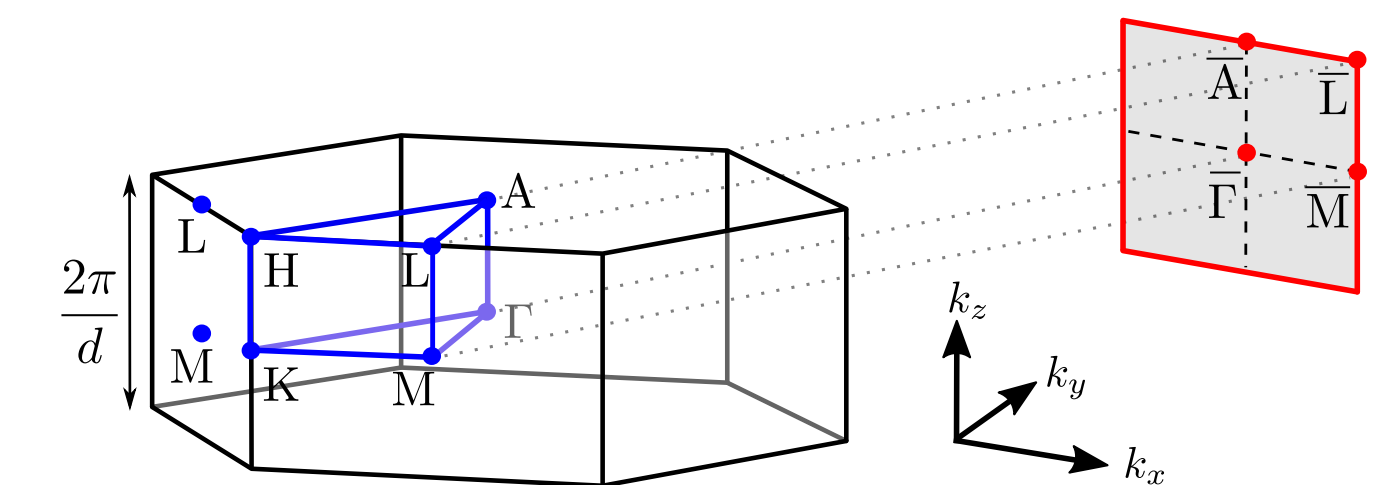


Purpose:

- influence of twin plane types on topological phases
- comparison with pentagonal NWs

Method:

- topological invariant calculations - mirror Chern number C_m and \mathbb{Z}_2
- surface spectral Green's functions



Bulk BZ and surface BZ of a [111] heterostructure.

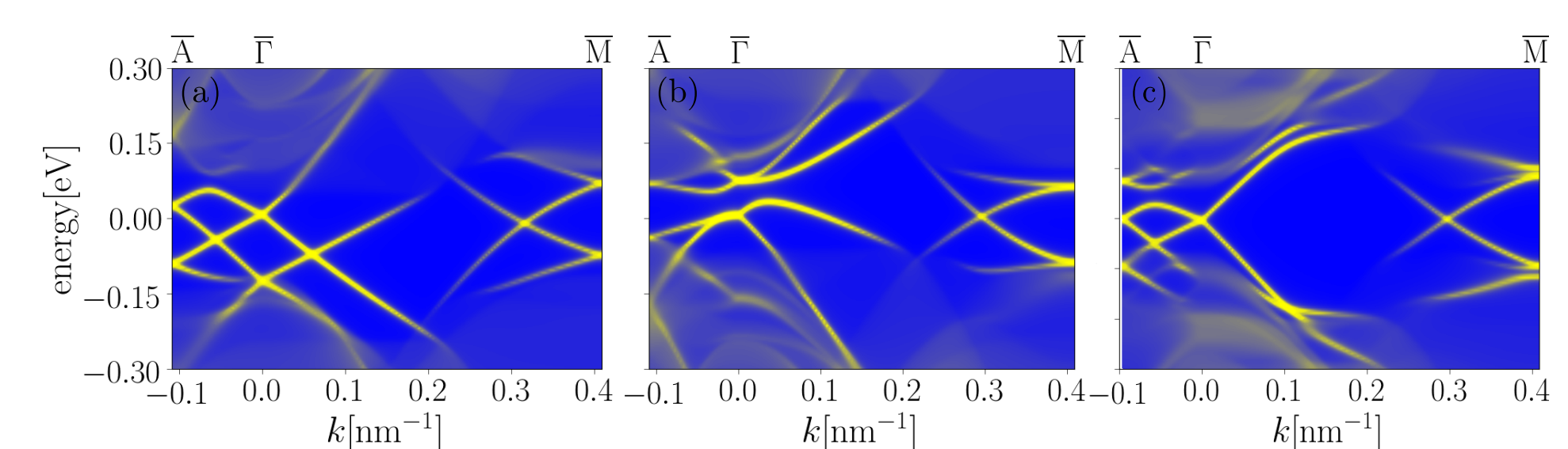


Figure: The $(10\bar{1})$ surface spectrum calculated for $d = 16$ monolayer height for both cationic (a) and anionic (b) TPs. (c) The spectral solutions for $d = 18$ monolayer height, hosting alternate TP kind. Table: The mirror Chern number C_m and \mathbb{Z}_2 invariants calculated for 3D heterostructures grown along [111] direction.

layers	cat-cat		an-an		cat-an	
	C_m	\mathbb{Z}_2	C_m	\mathbb{Z}_2	C_m	\mathbb{Z}_2
4	0	0	0	0	-	-
6	-	-	-	-	0	0
8	4	0	2	0	-	-
10	-	-	-	-	3	1
12	4	0	2	0	-	-
14	-	-	-	-	3	1
16	4	0	2	0	-	-
18	-	-	-	-	3	1

Conclusions

In C_5 -symmetric NW, the Dirac point exists only in $C_5 = -1$ subspace when the five TPs dividing the NW segments are cationic. However, exact crystalline symmetry is not necessary for the crossing to emerge. The Dirac point still persists even after C_5 is weakly broken, because topological CS or topological hinge states are protected by time-reversal symmetry.

The core and hinge topological states can be interpreted as hybridized edge states of five twin boundaries which effectively act as quantum spin Hall insulators.

References and Acknowledgment

- [1] T. H. Hsieh et al., Nat. Commun. **3**, 982 (2012)
- [2] D. Janaszko et al, the XVIIth International Conference on Electron Microscopy (2020)
- [3] P. Dziawa et al., Nat. mater. **11**, 1023 (2012)

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